

Data Sheet January 2000 File Number 3400.3

30A, 1200V Ultrafast Dual Diode

The RURG30120CC is an ultrafast dual diode with soft recovery characteristic (t_{rr} < 110ns). It has low forward voltage drop and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimize ringing and electrical noise in many power switching circuits, reducing power loss in the switching transistors.

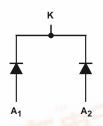
Formally developmental type TA49031.

Ordering Information

PART NUMBER	PACKAGE	BRAND		
RURG30120CC	TO-247	URG30120C		

NOTE: When ordering, use the entire part number.

Symbol



Features

	Ultrafast with Soft Recovery	
•	Operating Temperature	75°C
•	Reverse Voltage	200V

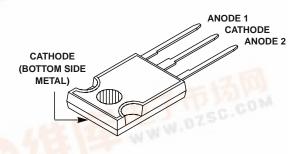
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supplies
- Power Switching Circuits
- General Purpose

Package

JEDEC STYLE TO-247



Absolute Maximum Ratings (Per Leg) T_C = 25°C, Unless Otherwise Specified

	RURG30120CC	UNITS
Peak Repetitive Reverse VoltageVRRM	1200	V
Working Peak Reverse Voltage	1200	V
DC Blocking Voltage	1200	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_{C} = 110^{\circ}C$)	30	Α
Repetitive Peak Surge CurrentI _{FRM} (Square Wave, 20kHz)	60	Α
Nonrepetitive Peak Surge Current	300	Α
Maximum Power Dissipation	125	W
Avalanche Energy (See Figures 7 and 8)	30	mJ
Operating and Storage Temperature	-65 to 175	οС



RURG30120CC

Electrical Specifications (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V _F	I _F = 30A	-	-	2.1	V
	I _F = 30A, T _C = 150 ^o C	-	-	1.9	V
I _R	V _R = 1200V	-	-	250	μΑ
	V _R = 1200V, T _C = 150°C	-	-	1	mA
t _{rr}	I _F = 1A, dI _F /dt = 100A/μs	-	-	110	ns
	I _F = 30A, dI _F /dt = 100A/μs	-	-	150	ns
ta	I _F = 30A, dI _F /dt = 100A/μs	-	90	-	ns
t _b	I _F = 30A, dI _F /dt = 100A/μs	-	45	-	ns
$R_{ heta JC}$		-	-	1.2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

 t_{rr} = Reverse recovery time (See Figure 6), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current (See Figure 6).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 6).

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

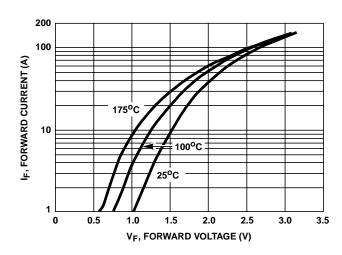


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

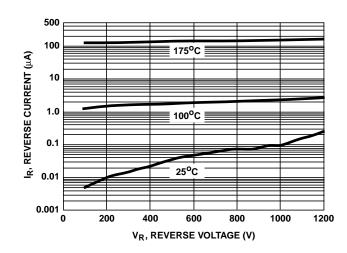


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

RURG30120CC

Typical Performance Curves (Continued)

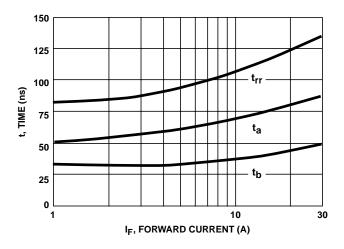


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

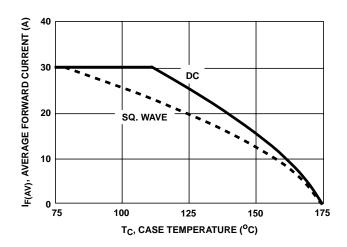


FIGURE 4. CURRENT DERATING CURVE

Test Circuits and Waveforms

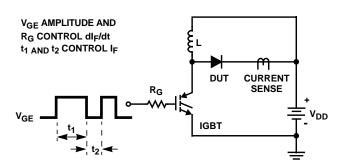


FIGURE 5. t_{rr} TEST CIRCUIT

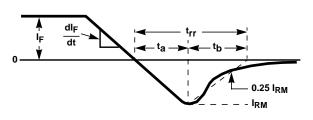


FIGURE 6. t_{rr} WAVEFORMS AND DEFINITIONS

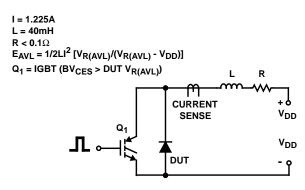


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

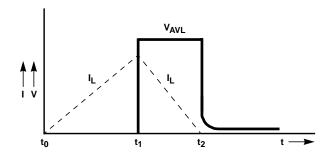


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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